

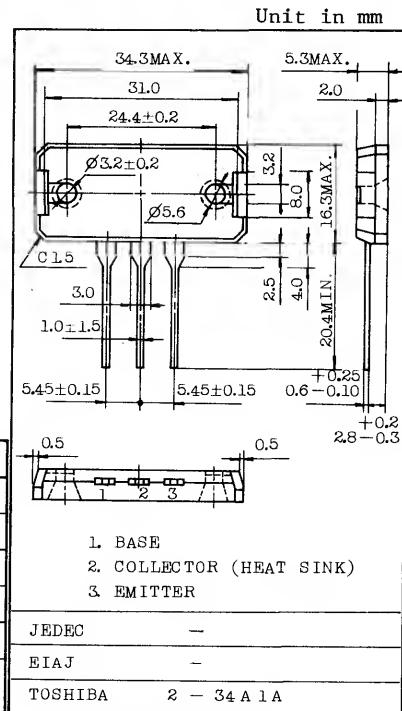
POWER AMPLIFIER APPLICATIONS.

FEATURES:

- High Breakdown Voltage : $V_{CEO} = -160V$
- High Transition Frequency : $f_T = 60MHz$ (Typ.)
- Complementary to 2SC2565.
- Recommended for 100W High-Fidelity Audio Frequency Amplifier Output Stage.

MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-160	V
Collector-Emitter Voltage	V_{CEO}	-160	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-15	A
Emitter Current	I_E	15	A
Collector Power Dissipation (Tc=25°C)	P_C	150	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C



Weight : 10.8g

ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = -160V, I_E = 0$	-	-	-50	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -5V, I_C = 0$	-	-	-50	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -0.1A, I_B = 0$	-160	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -0.01A, I_C = 0$	-5	-	-	V
DC Current Gain	$h_{FE}(1)$ (Note)	$V_{CE} = -5V, I_C = -1A$	55	-	240	
	$h_{FE}(2)$	$V_{CE} = -5V, I_C = -5A$	40	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -5A, I_B = -0.5A$	-	-	-2.0	V
Base-Emitter Voltage	V_{BE}	$V_{CE} = -5V, I_C = -5A$	-	-	-2.0	V
Transition Frequency	f_T	$V_{CE} = -10V, I_C = -1A$	-	60	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10V, I_E = 0, f = 1MHz$	-	350	-	pF

Note : $h_{FE}(1)$ Classification R : 55~110, O : 80~160, Y : 120~240

